NSN 5961-00-093-9175

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-093-9175 **Inclosure Material:** Metal **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.5 on voltage, forward voltage drop, dc and 65.0 reverse voltage, peak **Current Rating Per Characteristic:** 0.05 microamperes forward current, average peak **Capacitance Rating In Picofarads:** 2.0 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No